

## Data Sheet

**AD8675**

### FEATURES

- Very low voltage noise: 2.8 nV/ $\sqrt{\text{Hz}}$
- Rail-to-rail output swing
- Low input bias current: 2 nA maximum
- Very low offset voltage: 75  $\mu\text{V}$  maximum
- Low input offset drift: 0.6  $\mu\text{V}/^{\circ}\text{C}$  maximum
- Very high gain: 120 dB
- Wide bandwidth: 10 MHz typical
- $\pm 5 \text{ V}$  to  $\pm 18 \text{ V}$  operation

### APPLICATIONS

- Precision instrumentation
- PLL filters
- Laser diode control loops
- Strain gage amplifiers
- Medical instrumentation
- Thermocouple amplifiers

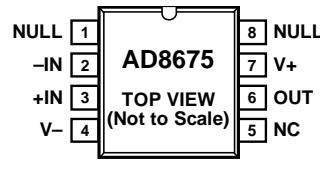
### GENERAL DESCRIPTION

The AD8675 precision operational amplifier has ultralow offset, drift, and voltage noise combined with very low input bias currents over the full operating temperature range. The AD8675 is a precision, wide bandwidth op amp featuring rail-to-rail output swings and very low noise. Operation is fully specified from  $\pm 5 \text{ V}$  to  $\pm 15 \text{ V}$ .

The AD8675 features a rail-to-rail output like that of the [OP184](#), but with wide bandwidth and even lower voltage noise, combined with the precision and low power consumption like that of the industry-standard OP07 amplifier. Unlike other low noise, rail-to-rail op amps, the AD8675 has very low input bias current and low input current noise.

With typical offset voltage of only 10  $\mu\text{V}$ , offset drift of 0.2  $\mu\text{V}/^{\circ}\text{C}$ , and noise of only 0.10  $\mu\text{V}$  p-p (0.1 Hz to 10 Hz), the AD8675 is perfectly suited for applications where large error sources cannot be tolerated. For applications with even lower offset tolerances, the proprietary nulling capability allows a combination of both device and system offset errors up to 3.5 mV (referred to the input) to be compensated externally. Unlike previous circuits, the AD8675 accommodates this adjustment without adversely affecting the offset drift, CMRR, and PSRR of the amplifier. Precision instrumentation, PLL, and other precision filter circuits, position and pressure sensors, medical instrumentation, and strain gage amplifiers benefit greatly from the very low noise, low input bias current, and wide bandwidth. Many systems can

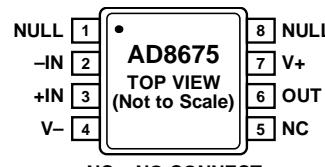
### PIN CONFIGURATIONS



NC = NO CONNECT

Figure 1. 8-Lead SOIC\_N (R-8)

05564-001



NC = NO CONNECT

Figure 2. 8-Lead MSOP (RM-8)

05564-002

take advantage of the low noise, dc precision, and rail-to-rail output swing provided by the AD8675 to maximize SNR and dynamic range.

The smaller packages and low power consumption afforded by the AD8675 allow maximum channel density or minimum board size for space-critical equipment.

The AD8675 is specified for the extended industrial temperature range ( $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ ). The AD8675 amplifier is available in the tiny 8-lead MSOP, and the popular 8-lead, narrow SOIC, RoHS compliant packages. MSOP packaged devices are only available in tape and reel format.

For the dual version of this ultraprecision, rail-to-rail op amp, see the [AD8676](#) data sheet.

The AD8675 and AD8676 are members of a growing series of low noise op amps offered by Analog Devices, Inc.

**Table 1. Voltage Noise**

Package	0.9 nV	1.1 nV	1.8 nV	2.8 nV	3.8 nV
Single	<a href="#">AD797</a>	<a href="#">AD8597</a>	<a href="#">ADA4004-1</a>	<a href="#">AD8675</a>	<a href="#">AD8671</a>
Dual		<a href="#">AD8599</a>	<a href="#">ADA4004-2</a>	<a href="#">AD8676</a>	<a href="#">AD8672</a>
Quad			<a href="#">ADA4004-4</a>		<a href="#">AD8674</a>

**Rev. D**

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## REVISION HISTORY

### 8/11—Rev. C to Rev. D

Added Input Capacitance, Common Mode Parameter and Input Capacitance, Differential Mode Parameter, Table 3..... 4

### 6/10—Rev. B to Rev. C

Changes to Figure 10..... 7

### 5/10—Rev. A to Rev. B

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Added Table 1; Renumbered Sequentially .....	1
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### 4/07—Rev. 0 to Rev. A

Added Figure 7 and Figure 8; Renumbered Sequentially .....

### 10/05—Revision 0: Initial Version

## SPECIFICATIONS

### ELECTRICAL SPECIFICATIONS

$V_S = \pm 5.0$  V,  $V_{CM} = 0$  V,  $V_O = 0$  V,  $T_A = +25^\circ\text{C}$ , unless otherwise specified.

Table 2.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	$V_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	10	75		$\mu\text{V}$
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	12	240		$\mu\text{V}/^\circ\text{C}$
Input Bias Current	$I_B$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-2	+0.5	+2	nA
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-5.5	-2	+5.5	nA
Input Voltage Range	IVR	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-1	+0.1	+1	nA
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -3.0$ V to $+3.0$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	105	130		dB
Open-Loop Gain	$A_{VO}$	$R_L = 2 \text{ k}\Omega$ to ground, $V_O = -3.5$ V to $+3.5$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	120	126		dB
			117			dB
OUTPUT CHARACTERISTICS						
Output Voltage High	$V_{OH}$	$R_L = 10 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	4.90	4.95		V
		$R_L = 2 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	4.85			V
			4.80	4.90		V
			4.75			V
Output Voltage Low	$V_{OL}$	$R_L = 10 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-4.98	-4.90		V
		$R_L = 2 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		-4.85		V
				-4.91	-4.86	V
					-4.82	V
Short-Circuit Limit	$I_{SC}$			$\pm 35$		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5.0$ V to $\pm 15.0$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	120	140		dB
Supply Current/Amplifier	$I_{SY}$	$V_O = 0$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	120	2.3	2.7	mA
					3.4	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 2 \text{ k}\Omega$		2.5		$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP			10		MHz
NOISE PERFORMANCE						
Voltage Noise	$e_{n,p-p}$	0.1 Hz to 10 Hz		0.1		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1 \text{ kHz}$		2.8		$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 10 \text{ Hz}$		0.3		$\text{pA}/\sqrt{\text{Hz}}$

$V_S = \pm 15$  V,  $V_{CM} = 0$  V,  $V_O = 0$  V,  $T_A = +25^\circ\text{C}$ , unless otherwise specified.

Table 3.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	$V_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	10	75		$\mu\text{V}$
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	12	240		$\mu\text{V}/^\circ\text{C}$
Input Bias Current	$I_B$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-2	+0.5	+2	nA
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-4.5	+1	+4.5	nA
Input Voltage Range	IVR	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-1	+0.1	+1	nA
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -12.5$ V to $+12.5$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	114	130		dB
Open-Loop Gain	$A_{VO}$	$R_L = 2 \text{ k}\Omega$ to ground, $V_O = -13.5$ V to $+13.5$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	123	132		dB
Input Capacitance, Common Mode	$C_{INCM}$			3.8		pF
Input Capacitance, Differential Mode	$C_{INDM}$			9.6		pF
OUTPUT CHARACTERISTICS						
Output Voltage High	$V_{OH}$	$R_L = 10 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	14.85	14.92		V
		$R_L = 2 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	14.80			V
		$R_L = 10 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	14.60	14.80		V
		$R_L = 2 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	14.40			V
Output Voltage Low	$V_{OL}$	$R_L = 10 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		-14.96	-14.94	V
		$R_L = 2 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			-14.90	V
		$R_L = 10 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		-14.85	-14.75	V
		$R_L = 2 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			-14.69	V
Short-Circuit Limit	$I_{SC}$			$\pm 35$		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5.0$ V to $\pm 15.0$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	120	140		dB
Supply Current/Amplifier	$I_{SY}$	$V_O = 0$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	120	2.5	2.9	mA
					3.8	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 10 \text{ k}\Omega$		2.5		$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP			10		MHz
NOISE PERFORMANCE						
Voltage Noise	$e_{n,p-p}$	0.1 Hz to 10 Hz		0.1		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1 \text{ kHz}$		2.8		$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 10 \text{ Hz}$		0.3		$\text{pA}/\sqrt{\text{Hz}}$

## ABSOLUTE MAXIMUM RATINGS

Table 4.

Parameter	Rating
Supply Voltage	$\pm 18\text{V}$
Input Voltage	$\pm V_{\text{supply}}$
Input Current	$\pm 5\text{ mA}$
Differential Input Voltage	$\pm 0.7\text{ V}$
Output Short-Circuit Duration to GND	Indefinite
Storage Temperature Range RM-8, R-8 Packages	$-65^{\circ}\text{C}$ to $+150^{\circ}\text{C}$
Operating Temperature Range	$-40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$
Junction Temperature Range RM-8, R-8 Packages	$-65^{\circ}\text{C}$ to $+150^{\circ}\text{C}$
Lead Temperature Range (Soldering, 10 sec)	300°C
NULL Pins (Pin 1, Pin 8), Input Current Maximum	$<50\text{ }\mu\text{A}, V_S < V_+$

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL RESISTANCE

$\theta_{JA}$  is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages and measured using a standard 4-layer board, unless otherwise specified.

Table 5. Thermal Resistance

Package Type	$\theta_{JA}$	$\theta_{JC}$	Unit
8-Lead MSOP (RM-8)	142	45	$^{\circ}\text{C/W}$
8-Lead SOIC_N (R-8)	120	45	$^{\circ}\text{C/W}$

## ESD CAUTION



### ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## TYPICAL PERFORMANCE CHARACTERISTICS

$\pm 15 \text{ V}$  and  $\pm 5 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

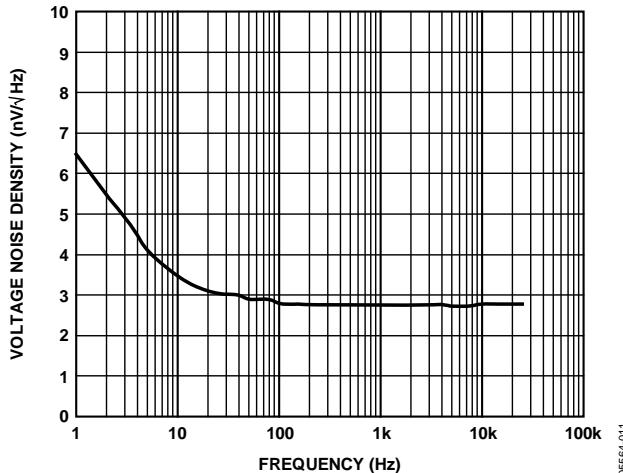


Figure 3. Voltage Noise Density vs. Frequency

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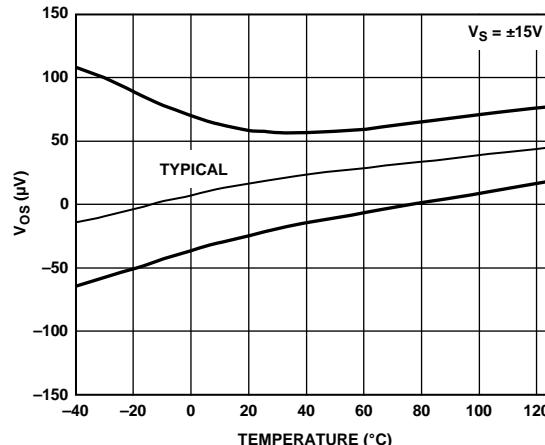


Figure 6. Offset Voltage vs. Temperature

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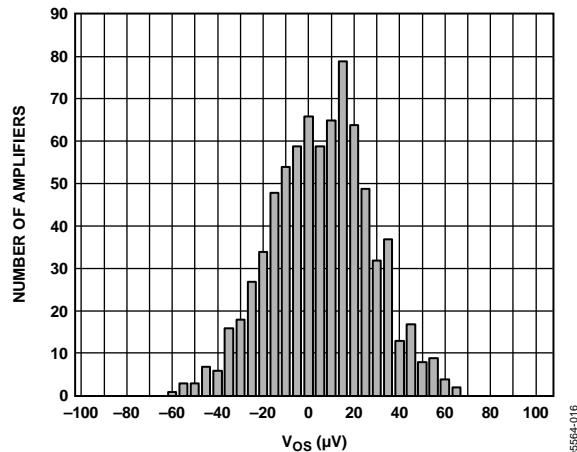


Figure 4. Input Offset Voltage Distribution

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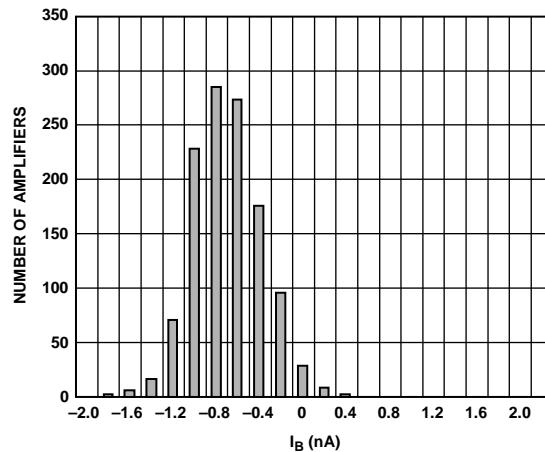


Figure 7. Input Bias Current,  $V_S = \pm 15 \text{ V}$

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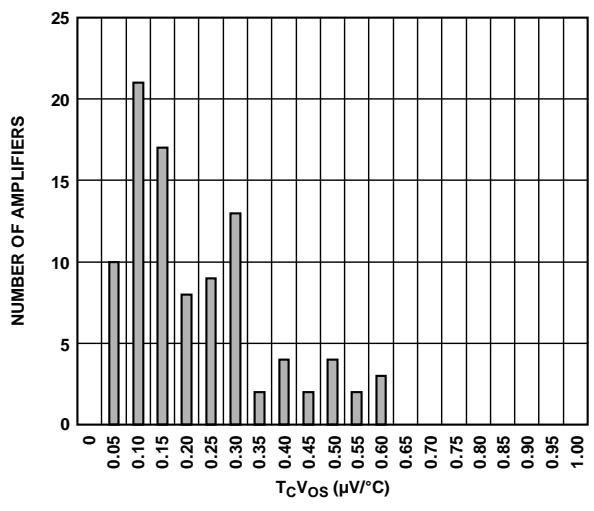


Figure 5.  $T_c V_{OS}$

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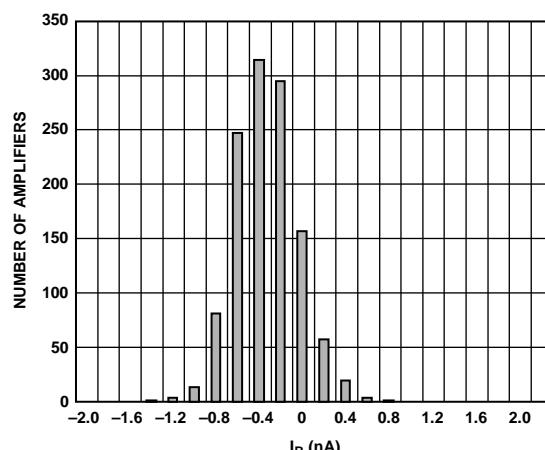
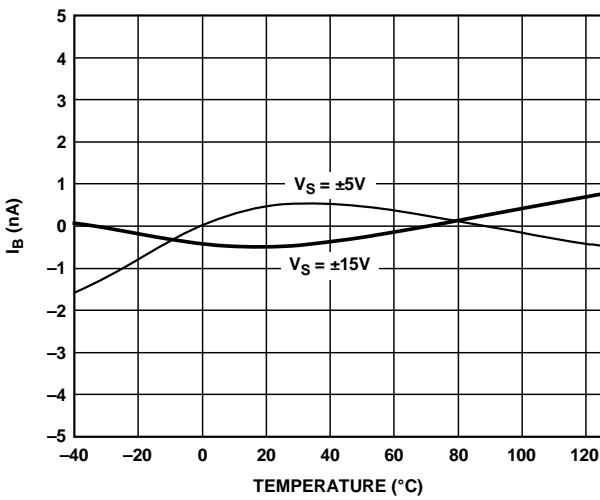
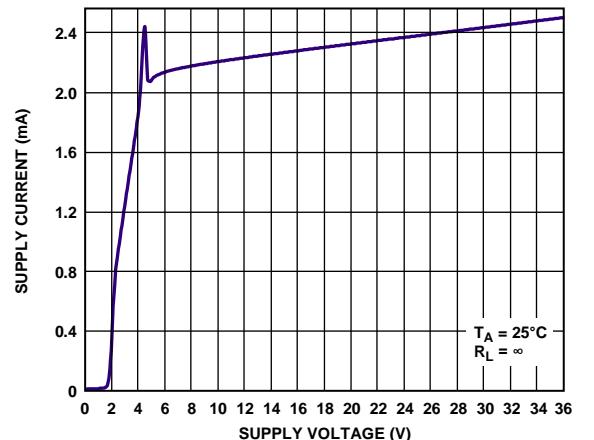


Figure 8. Input Bias Current,  $V_S = \pm 5 \text{ V}$

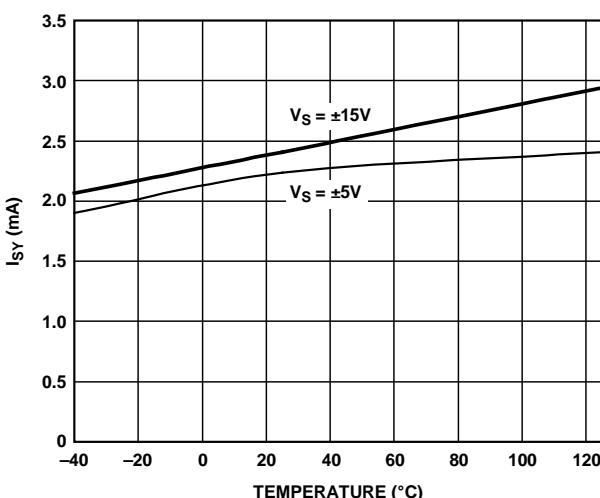
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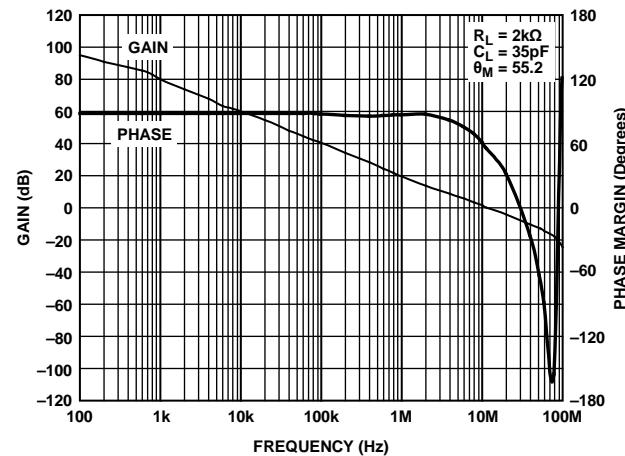
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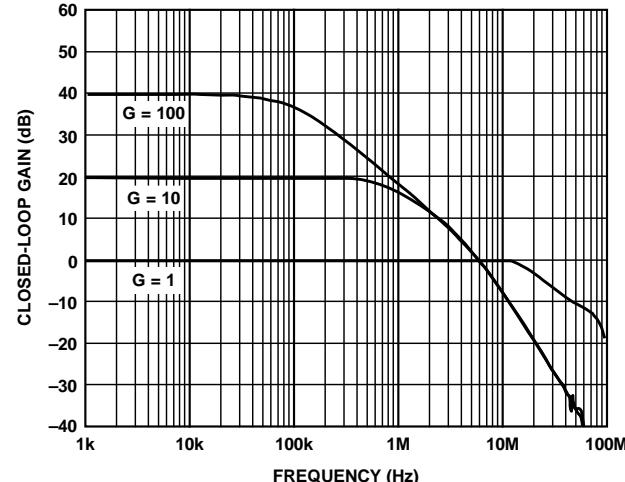
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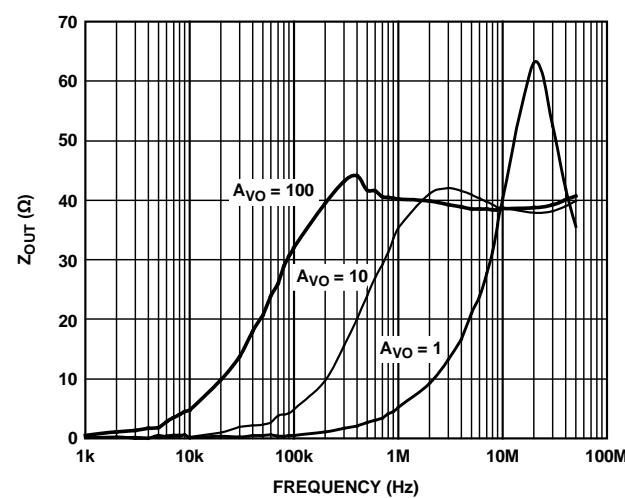
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05564-030



05564-015

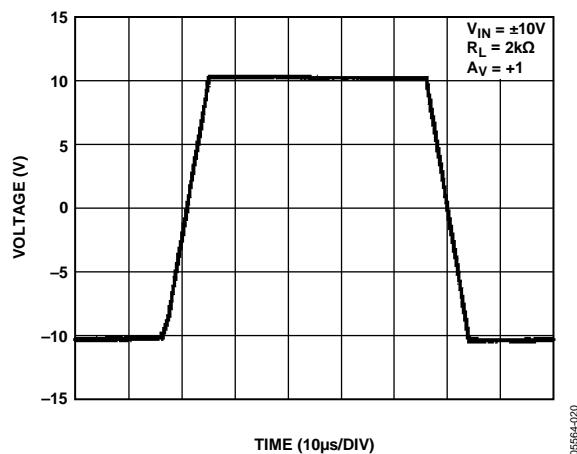
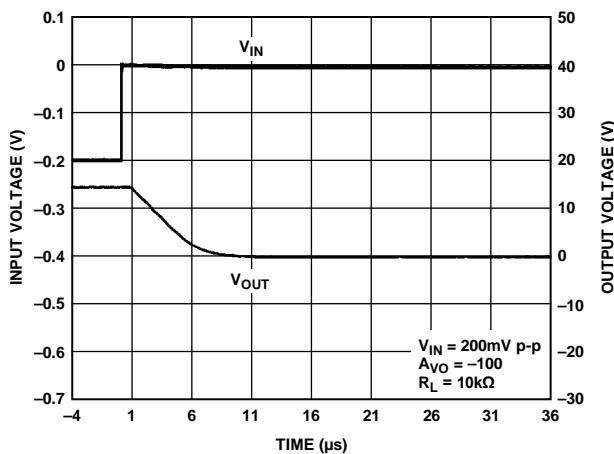
Figure 15. Large-Signal Transient Response,  $V_{SY} = \pm 15 V$ 

Figure 18. Positive Overvoltage Recovery

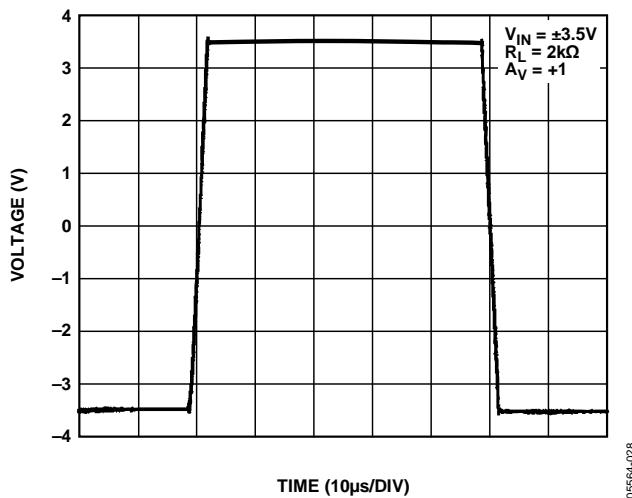
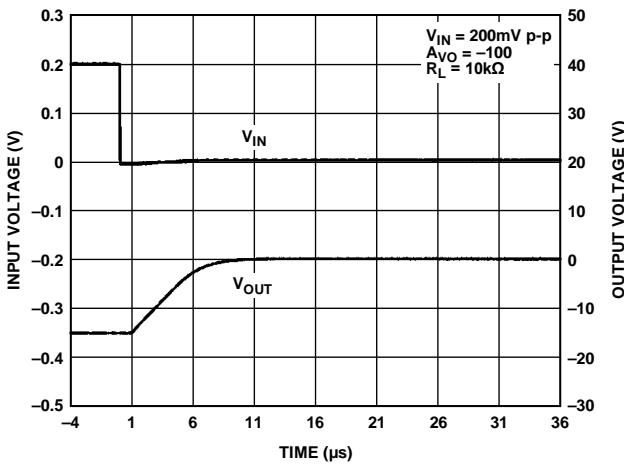
Figure 16. Large-Signal Transient Response,  $V_{SY} = \pm 5 V$ 

Figure 19. Negative Overvoltage Recovery

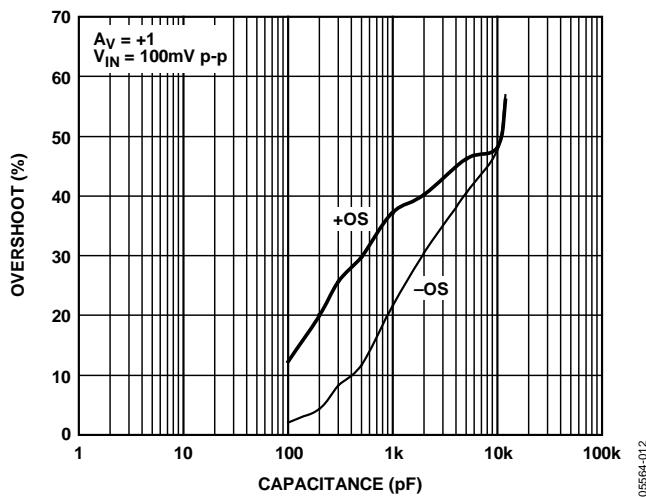


Figure 17. Small-Signal Overshoot vs. Load Capacitance

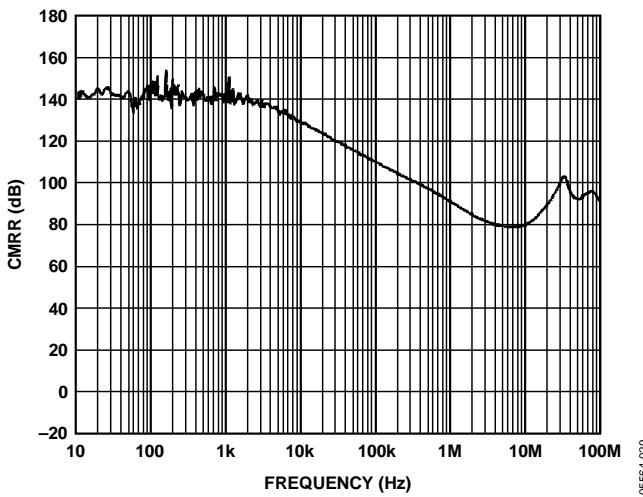
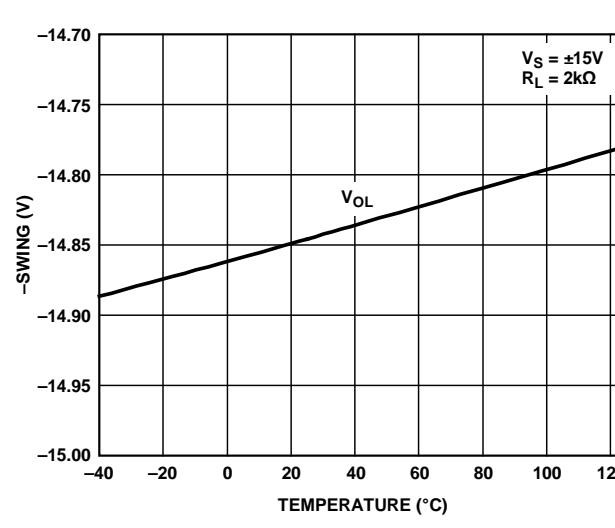
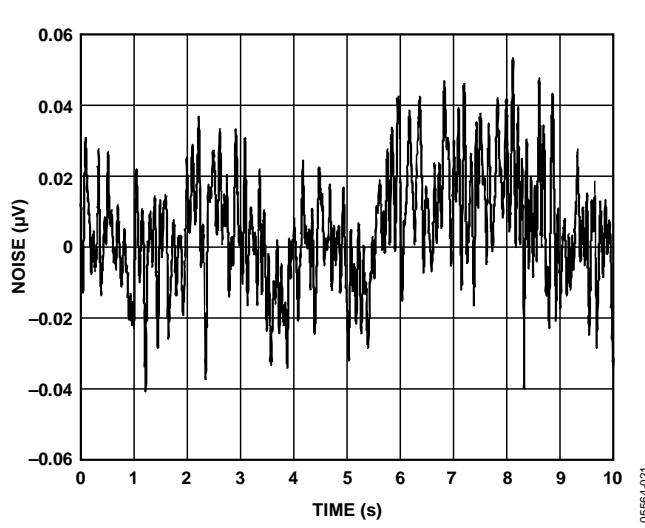
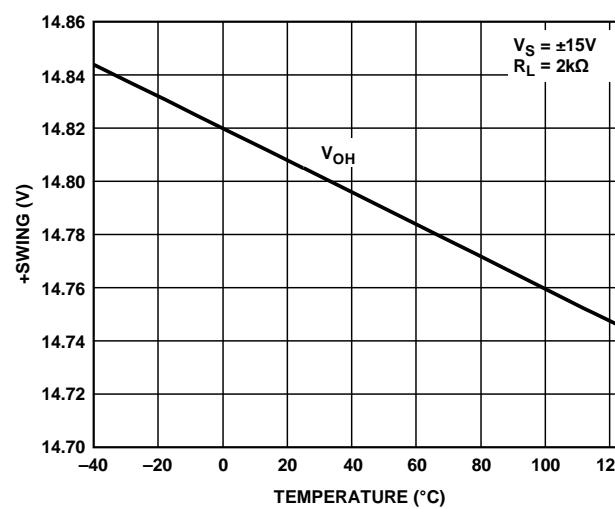
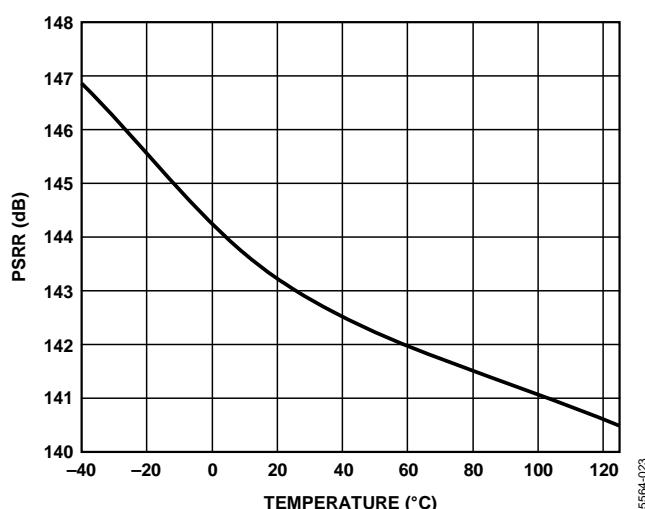
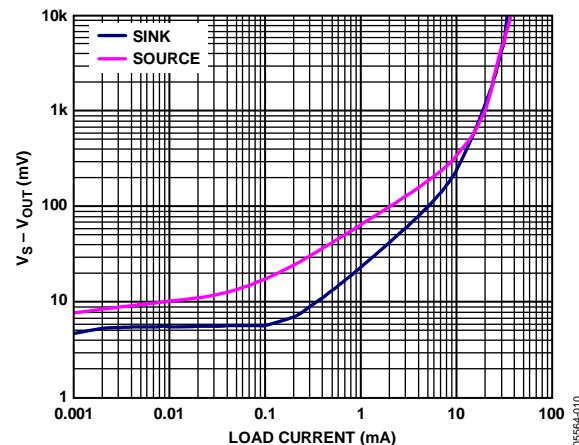
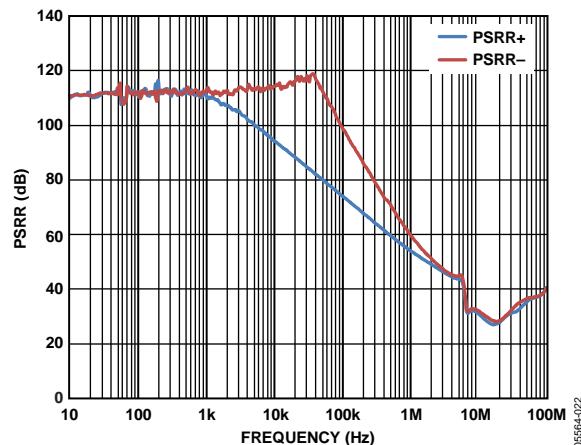


Figure 20. CMRR vs. Frequency



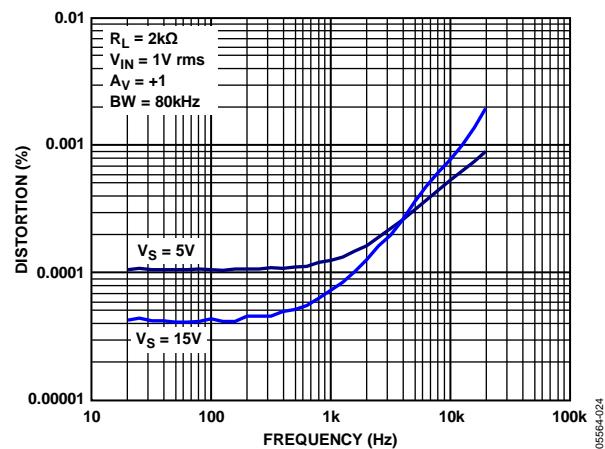


Figure 27. Distortion vs. Frequency

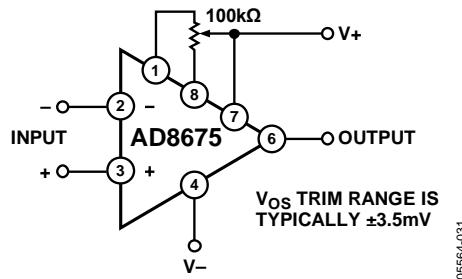
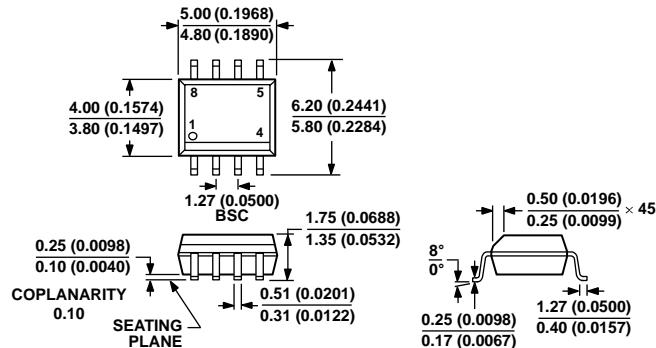
**TEST CIRCUIT**

Figure 28. Optional Offset Nulling Circuit

# OUTLINE DIMENSIONS

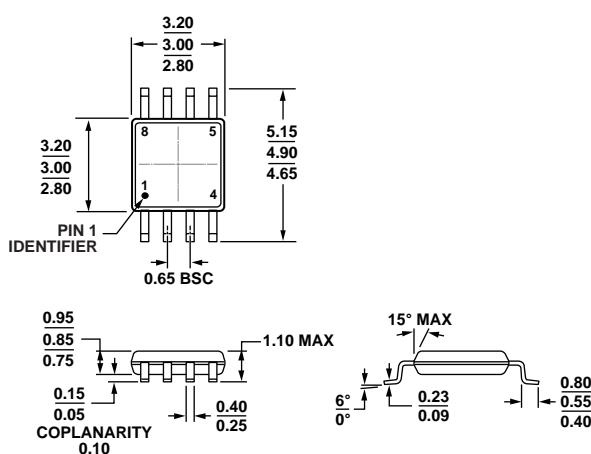


COMPLIANT TO JEDEC STANDARDS MS-012-AA

**CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS  
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR  
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.**

340

*Figure 29. 8-Lead Standard Small Outline Package [SOIC\_N]  
Narrow Body (R-8)*



0-07-2009-B

*Figure 30. 8-Lead Mini Small Outline Package [MSOP]  
(RM-8)  
Dimensions shown in millimeters*

## **ORDERING GUIDE**

Model <sup>1</sup>	Temperature Range	Package Description	Package Option	Branding
AD8675ARMZ	-40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A08
AD8675ARMZ-REEL	-40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A08
AD8675ARZ	-40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	
AD8675ARZ-REEL	-40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	
AD8675ARZ-REEL7	-40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	

<sup>1</sup> Z = RoHS Compliant Part.